I hereby certify that this correspondence is being deposited with the U.S. Postal Service as Express Mail, Airbill No. EV343595971US, in an envelope addressed to: MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date shown below.

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Docket No.: 291958171US4 Semitool Ref No. P98-0025US8 (PATENT)

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

TRADE hen et al.

Application No.: 10/695,419

Confirmation No.: 4483

Filed: October 27, 2003

Art Unit: 2818

For: APPARATUS AND METHOD FOR

Examiner: P. T. Dang

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INFORMATION DISCLOSURE STATEMENT (IDS)

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO/SB/08. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is filed more than three months after the U.S. filing date, OR more than three months after the date of entry of the national stage of a PCT application, AND after the mailing date of the first Office Action on the merits, whichever occurs first, but before the mailing date of a Final Office Action or Notice of Allowance (37 CFR 1.97(c)).

Application No.: 10/695,419 Docket No.: 291958171US4

Copies of the references on the PTO/SB/08 are not provided.

The references are not supplied because they were previously cited by or submitted to the Office in a prior application number 10/302,711, filed November 22, 2002, Patent No. 6,638,410 and relied upon in this application for an earlier filing date under 35 U.S.C. 120.

Our check in the amount of \$180.00 covering the fee set forth in 37 CFR 1.17(p) is enclosed. The Director is hereby authorized to charge any deficiency in the fees filed, asserted to be filed or which should have been filed herewith (or with any paper hereafter filed in this application by this firm) to our Deposit Account No. 50-0665, under Order No. 291958171US4.

Dated: Vune 24, 2004

Respectfully submitted,

Paul T. Parker

Registration No.: 38,264

PERKINS COIE LLP

P.O. Box 1247

Seattle, Washington 98111-1247

(206) 359-8000

(206) 359-7198 (Fax)

Attorney for Applicant

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Substitute for form 1449A/B/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 1

	Complete if Known					
Application Number	10/695,419-Conf. #4483					
Filing Date	October 27, 2003					
First Named Inventor	LinLin Chen					
Art Unit	2818					
Examiner Name	P. T. Dang					
Attorney Docket Number	291958171US4					

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S	TATEMENT E	BY /	APPLICANT	First Named Inventor	LinLin Chen	
_				Art Unit	2818	
	(Use as many sh	eets as	necessary)	Examiner Name	P. T. Dang	
Sheet	2	of	4	Attorney Docket Number	291958171US4	

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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not *EXAMINER: Initial if reterence considered, whether or not citation is in conformance with MPEP 609. Draw line through citation is not in conformance and not considered. Include copy of this form with next communication to applicant "**CITE NO.: Those patent(s) or publication(s) which are marked with an double saterisk (**) next to the Cite No. are not supplied because they were previously cited by or submitted to the Office in a prior application relied upon in this application for an earlier filling date under 35 U.S.C. 120. ¹Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁵Applicant is to place a check mark here if English language Translation is

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""				Application Number	10/695,419-Conf. #4483	
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S	TATEMENT	BY A	APPLICANT	First Named Inventor	LinLin Chen	
				Art Unit	2818	
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				Art Unit	2818	
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.

Examiner	Date	
Signature	Considered	
U.S. Martin	Considered	